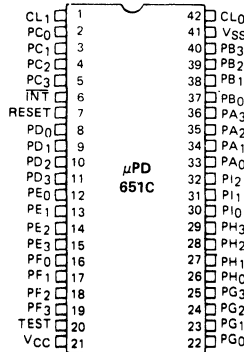


4-BIT SINGLE CHIP MICROCOMPUTER

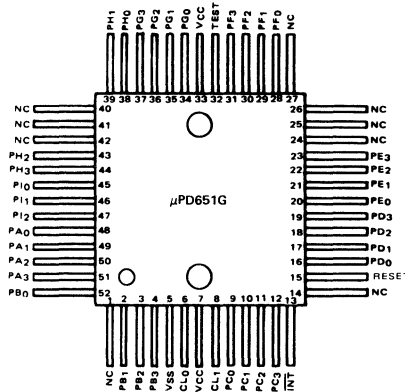
DESCRIPTION The μPD651 is a μCOM-44 4-bit single chip microcomputer manufactured with a low-power-consumption CMOS process, allowing use of a single +5V power supply. The μPD651 provides all of the hardware features of the μCOM-44 family, except that it has two subroutine stack levels to enhance software development. The μPD651 executes all 58 instructions of the μCOM-44 instruction set, and it is available either in a 42-pin Dual-in-line package (μPD651C), or in a space-saving 52-pin Flat-package (μPD651G).

PIN CONFIGURATION



PIN NAMES

PA ₀ -PA ₃	Input Port A
PB ₀ -PB ₃	Input Port B
PC ₀ -PC ₃	Input/Output Port C
PD ₀ -PD ₃	Input/Output Port D
PE ₀ -PE ₃	Output Port E
PF ₀ -PF ₃	Output Port F
PG ₀ -PG ₃	Output Port G
PH ₀ -PH ₃	Output Port H
PI ₀ -PI ₂	Output Port I
INT	Interrupt Input
CL ₀ -CL ₁	External Clock Signals
RESET	Reset
VCC	Power Supply Positive
VSS	Ground
TEST	Factory Test Pin (Connect to VCC)
NC	No Connection



ABSOLUTE MAXIMUM RATINGS*

Operating Temperature	-30°C to +85°C
Storage Temperature	-55°C to +125°C
Supply Voltage	-0.3 to +7.0 Volts
Input Voltages (Port A through D, INT, RESET)	-0.3 to +7.3 Volts
Output Voltages	-0.3 to +7.3 Volts
Output Current (Ports C through I, each bit)	2.5 mA
(Total, all ports)	28 mA

COMMENT: Stress above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

*T_a = 25°C

μPD651

T_a = -30°C to +85°C; V_{CC} = +5V ±10%

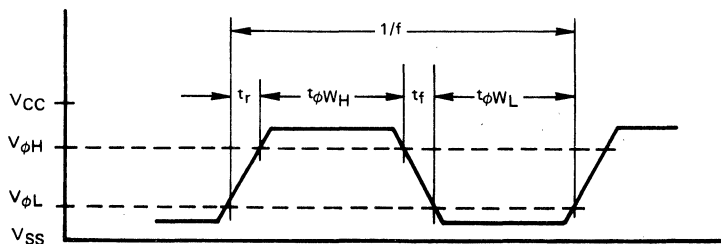
PARAMETER	SYMBOL	LIMITS			UNIT	TEST CONDITIONS
		MIN	TYP	MAX		
Input Voltage High	V _{IH}	0.7 V _{CC}		V _{CC}	V	Ports A through D, $\overline{\text{INT}}/\text{RESET}$
Input Voltage Low	V _{IL}	0		0.3 V _{CC}	V	Ports A through D, $\overline{\text{INT}}/\text{RESET}$
Clock Voltage High	V _{φH}	0.7 V _{CC}		V _{CC}	V	CL ₀ Input, External Clock
Clock Voltage Low	V _{φL}	0		0.3 V _{CC}	V	CL ₀ Input, External Clock
Input Leakage Current High	I _{LIH}			+10	μA	Ports A through D, $\overline{\text{INT}}/\text{RESET}$, V _I = V _{CC}
Input Leakage Current Low	I _{LIL}			-10	μA	Ports A through D, $\overline{\text{INT}}/\text{RESET}$, V _I = 0V
Clock Input Leakage Current High	I _{LφH}			+200	μA	CL ₀ Input, V _{φH} = V _{CC}
Clock Input Leakage Current Low	I _{LφL}			-200	μA	CL ₀ Input, V _{φL} = 0V
Output Voltage High	V _{OH1}	V _{CC} - 0.5			V	Ports C through I, I _{OH} = -1.0 mA
	V _{OH2}	V _{CC} - 2.5			V	Ports C through I, I _{OH} = -2.0 mA
Output Voltage Low	V _{OL1}			+0.6	V	Ports E through I, I _{OL} = +2.0 mA
	V _{OL2}			+0.4	V	Ports E through I, I _{OL} = +1.2 mA
Output Leakage Current Low	I _{LOL}			-10	μA	Ports C, D, V _O = 0V
Supply Current	I _{CC}		+0.8	+2.0	mA	

DC CHARACTERISTICS

T_a = -30°C to +85°C; V_{CC} = +5 ± 10%

PARAMETER	SYMBOL	LIMITS			UNIT	TEST CONDITIONS
		MIN	TYP	MAX		
Oscillator Frequency	f	150		440	KHz	
Rise and Fall Times	t _r , t _f	0		0.3	μS	
Clock Pulse Width High	t _{φWH}	0.5		5.6	μS	EXTERNAL CLOCK
Clock Pulse Width Low	t _{φWL}	0.5		5.6	μS	

AC CHARACTERISTICS



CLOCK WAVEFORM

T_a = 25°C

PARAMETER	SYMBOL	LIMITS			UNIT	TEST CONDITIONS
		MIN	TYP	MAX		
Input Capacitance	C _I			15	pF	f = 1 MHz
Output Capacitance	C _O			15	pF	
Input/Output Capacitance	C _{IO}			15	pF	

CAPACITANCE